www.vishay.com

VS-10ETF10FP-M3, VS-10ETF12FP-M3

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A



2L TO-220 FullPAK

PRIMARY CHARACTERISTICS					
I _{F(AV)}	10 A				
V _R	1000 V, 1200 V				
V _F at I _F	1.33 V				
I _{FSM}	140 A				
t _{rr}	80 ns				
T _J max.	150 °C				
Snap factor	0.6				
Package	2L TO-220 FullPAK				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operation junction temperature
 Designed and qualified according to JEDEC[®]-JESD 47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V _{RRM}		1000, 1200	V			
I _{F(AV)}	Sinusoidal waveform	10	А			
I _{FSM}		140				
t _{rr}	1 A, 100 A/μs	80	ns			
V _F	10 A, T _J = 25 °C	1.33	V			
TJ		-40 to +150	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-10ETF10FP-M3	1000	1100	4				
VS-10ETF12FP-M3	1200	1300	4				

Revision: 15-Sep-17 1 Document Number: 96294 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



FREE



Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	BOL TEST CONDITIONS VALUES		UNITS
Maximum average forward current	I _{F(AV)}	$T_{C} = 95 \text{ °C}$, 180° conduction half sine wave	10	
Maximum peak one cycle	1	10 ms sine pulse, rated V_{RRM} applied	115	А
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	140	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	66	A ² s
		10 ms sine pulse, no voltage reapplied	94	A-S
Maximum I²√t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.33	V
Forward slope resistance	r _t	T _J = 150 °C		22.9	mΩ
Threshold voltage	V _{F(TO)}			0.96	V
Maximum reverse leakage current		T _J = 25 °C		0.1	mA
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	4	

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	Lat 10 A	310	ns	I _{FM}
Reverse recovery current	I _{rr}	l _F at 10 A _{pk} 25 A/µs	4.7	А	
Reverse recovery charge	Q _{rr}	25 °C	1.05	μC	$\frac{\text{dir}}{\text{dt}}$
Snap factor	S		0.6		

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistar junction to case	nce	R _{thJC}	DC operation	2.5	
Maximum thermal resistar junction to ambient	nce	R _{thJA}		62	°C/W
Typical thermal resistance case to heatsink	·,	R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
minimum				6 (5)	kgf ⋅ cm
Mounting torque maxim	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style 2L TO-220 FullPAK	10ETF10FP 10ETF12FP	

Revision: 15-Sep-17

Document Number: 96294



Vishay Semiconductors

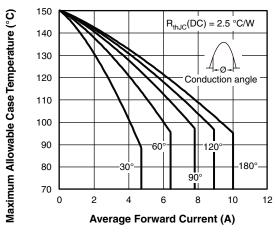


Fig. 1 - Current Rating Characteristics

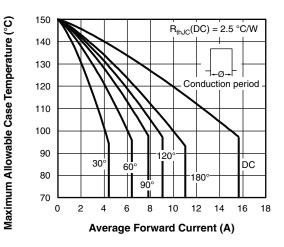


Fig. 2 - Current Rating Characteristics

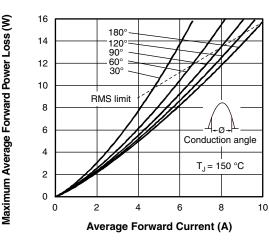


Fig. 3 - Forward Power Loss Characteristics

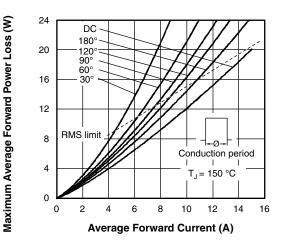


Fig. 4 - Forward Power Loss Characteristics

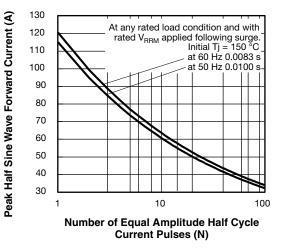


Fig. 5 - Maximum Non-Repetitive Surge Current

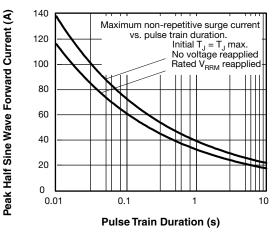


Fig. 6 - Maximum Non-Repetitive Surge Current

Revision: 15-Sep-17

3

Document Number: 96294

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors

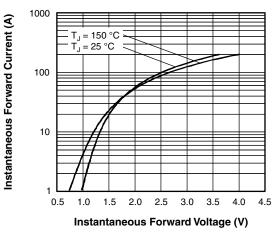


Fig. 7 - Forward Voltage Drop Characteristics

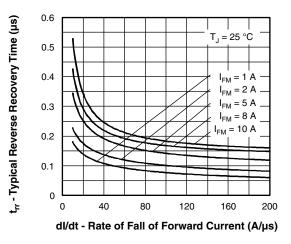


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^{\circ}C$

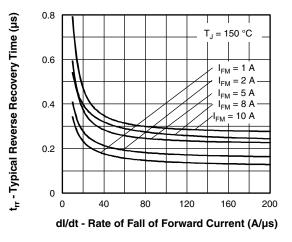


Fig. 9 - Recovery Time Characteristics, T_J = 150 $^\circ\text{C}$

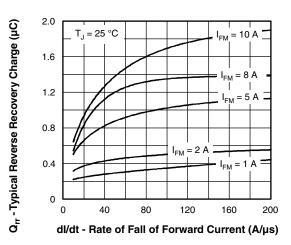
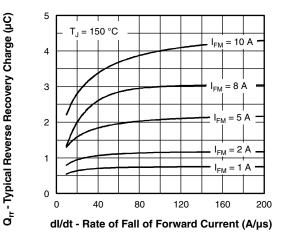


Fig. 10 - Recovery Charge Characteristics, $T_J = 25 \ ^{\circ}C$





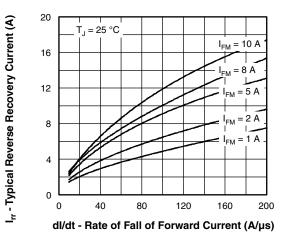


Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

Revision: 15-Sep-17

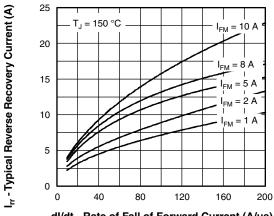
4

Document Number: 96294

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, $T_J = 150$ °C

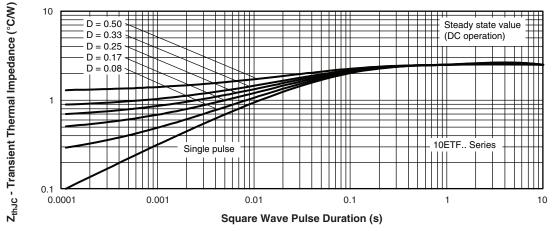
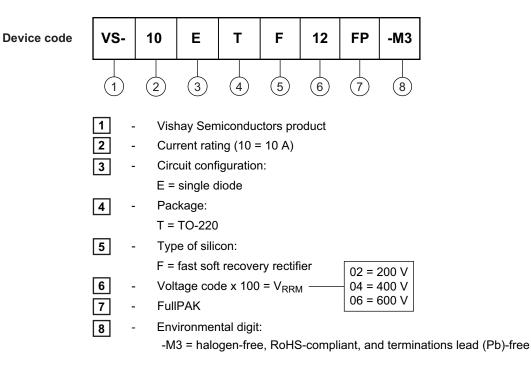


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



Vishay Semiconductors

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

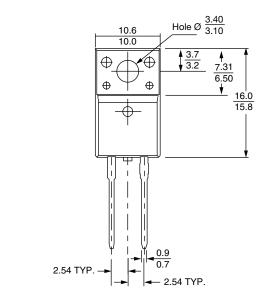
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96157					
Part marking information	www.vishay.com/doc?95392				

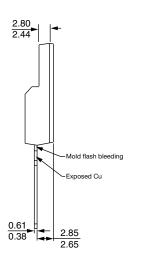


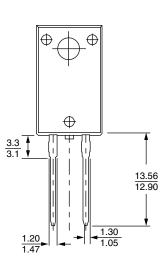
Vishay Semiconductors

2L TO-220 FullPAK

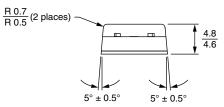
DIMENSIONS in millimeters







Bottom view





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.